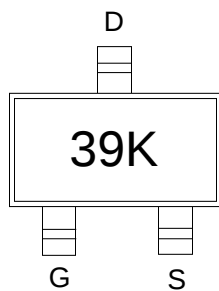


Features

- Lead Free Product is Acquired
- Surface Mount Package
- P-Channel Switch with Low $R_{DS(on)}$
- Operated at Low Logic Level Gate Drive

Application

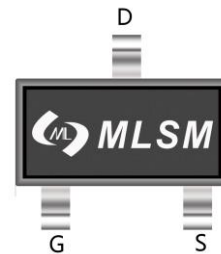
- Load/Power Switching
- Interfacing, Logic Switching
- Battery Management for Ultra Small Portable Electronics



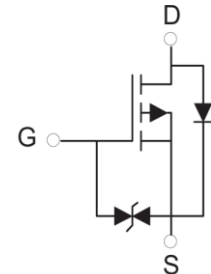
Marking and pin assignment

Product Summary

V_{DS}	$R_{DS(on)}$ TYP	I_D
-20V	380mΩ@-4.5V	-0.66A
	520mΩ@-2.5V	



SOT-523 top view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	-20	V
V_{GS}	Gate-Source Voltage	±12	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-55 to 150	°C
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ -0.66	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ -1.2	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ -0.66	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 0.15	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient	833	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS3139KT	SOT-523	39K	3,000	45,000	180,000	7"reel

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
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Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250μA	-20	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-20V, V _{GS} =0V	--	--	-1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±10V, V _{DS} =0V	--	--	±10	μA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250μA	-0.35	-0.65	-1.10	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =-4.5V, I _D =-1.0A	--	380	520	mΩ
		V _{GS} =-2.5V, I _D =-0.8A	--	520	700	mΩ

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

C _{ISS}	Input Capacitance	V _{DS} =-10V, V _{GS} =0V, f=1MHz	--	115	--	pF
C _{OSS}	Output Capacitance		--	15	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	8.8	--	pF

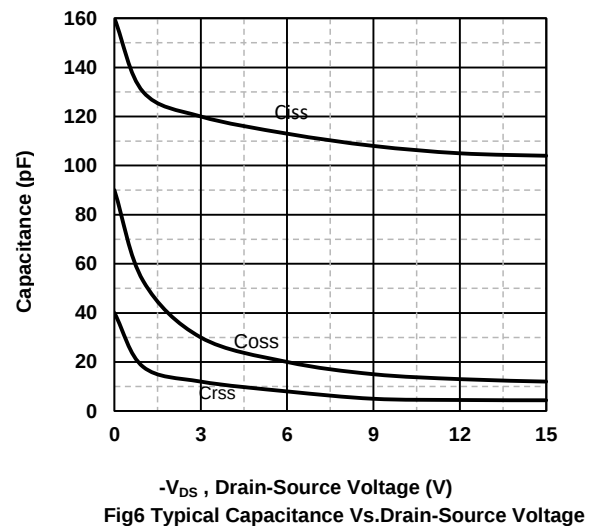
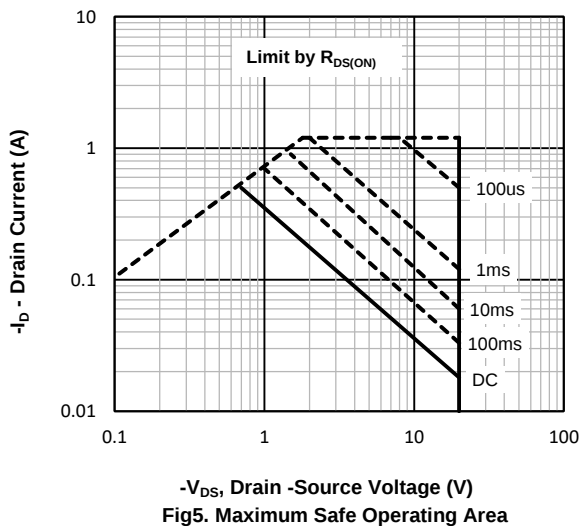
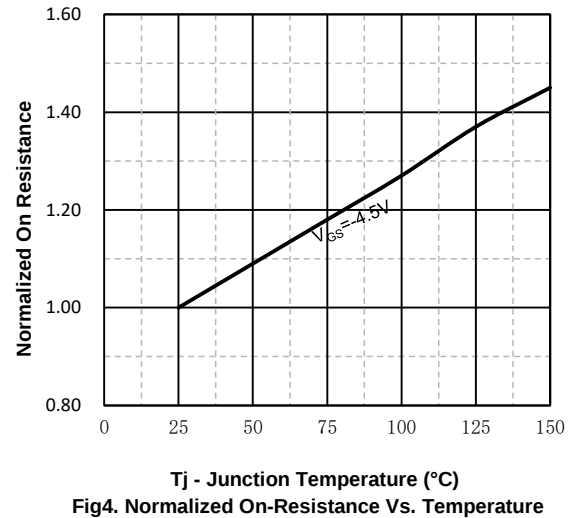
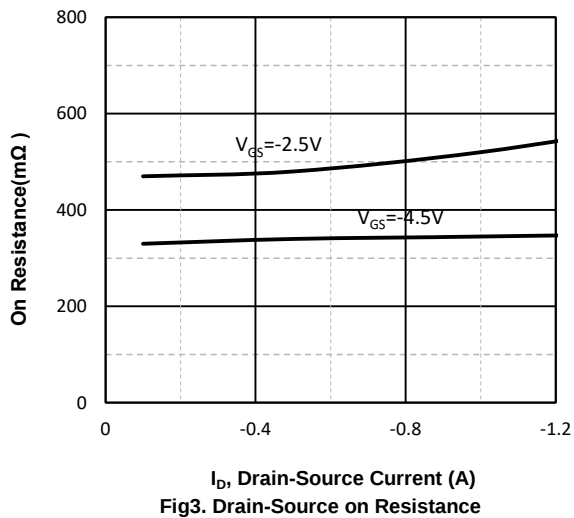
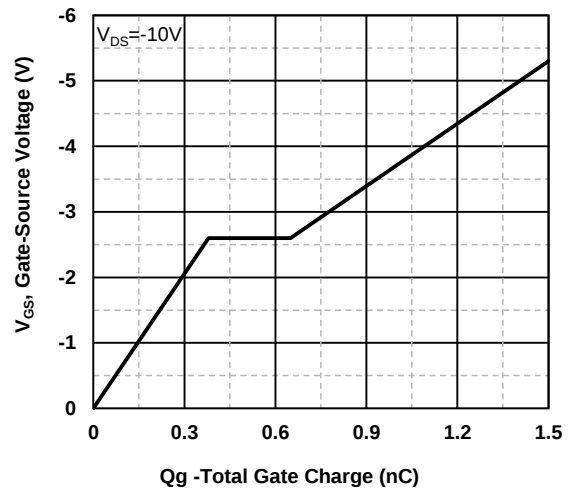
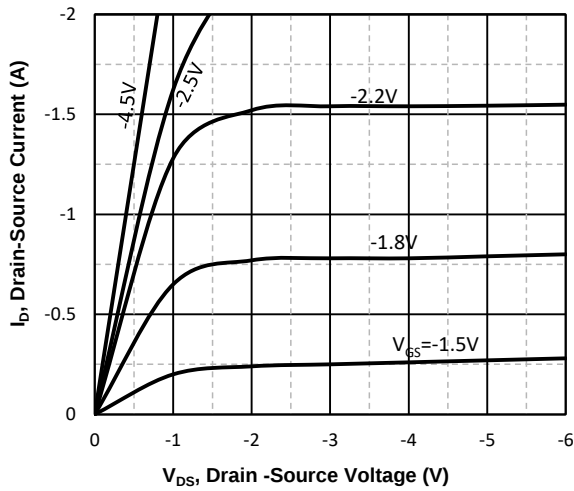
Switching Characteristics

Q _g	Total Gate Charge	V _{DD} =-10V, I _D =-0.5A, V _{GS} =-4.5V	--	1.25	--	nC
Q _{gs}	Gate Source Charge		--	0.35	--	nC
Q _{gd}	Gate Drain Charge		--	0.29	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =-10V, I _D =-0.2A, V _{GS} =-4.5V, R _G =10Ω	--	9	--	nS
t _r	Turn-on Rise Time		--	5.5	--	nS
t _{d(off)}	Turn-Off Delay Time		--	30.8	--	nS
t _f	Turn-Off Fall Time		--	20	--	nS

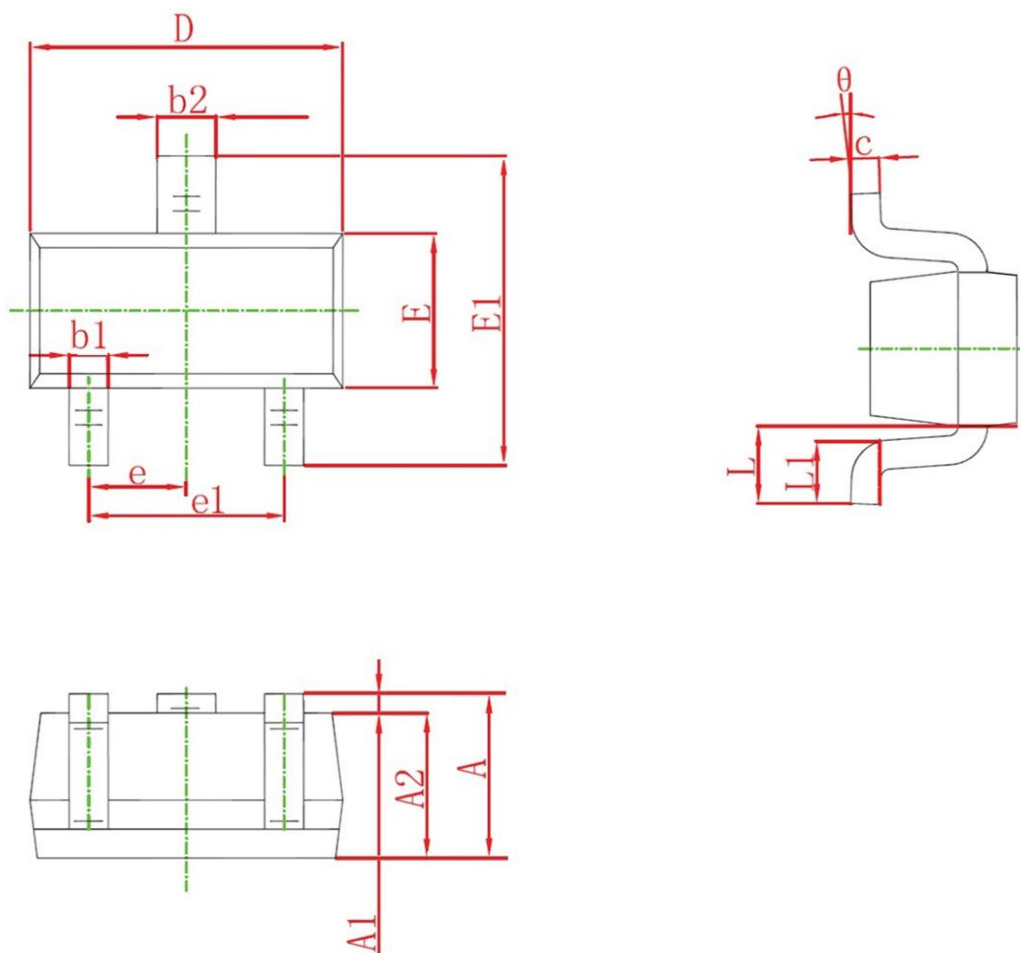
Source- Drain Diode Characteristics

V _{SD}	Forward on voltage	T _J =25°C, I _S =-0.66A	--	--	-1.2	V
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Typical Operating Characteristics



SOT-523 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500TYP		0.020TYP	
e1	0.900	1.100	0.035	0.043
L	0.400REF		0.016REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°